Emission at the excitonic resonances in GaAs quantum wells: The Excitons vs plasma problem revisited



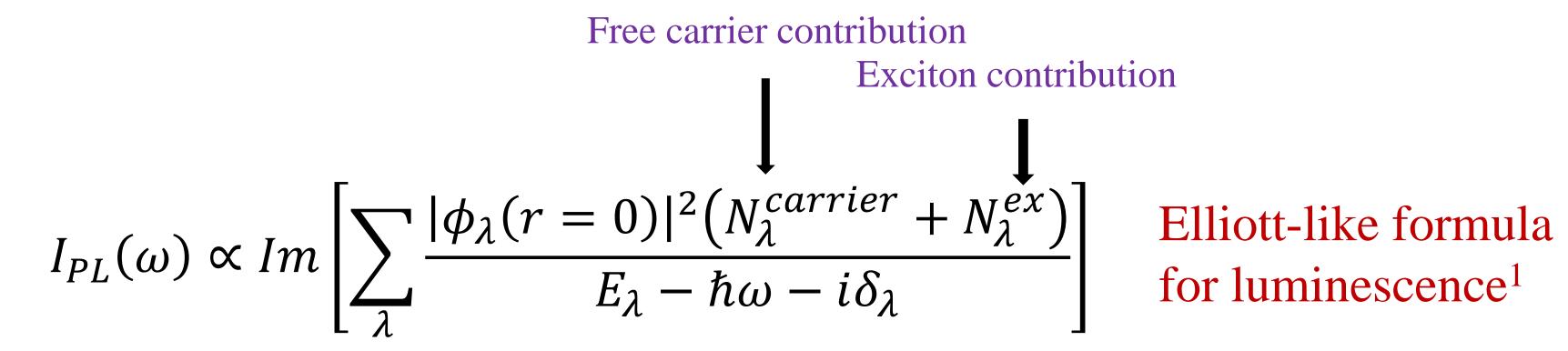
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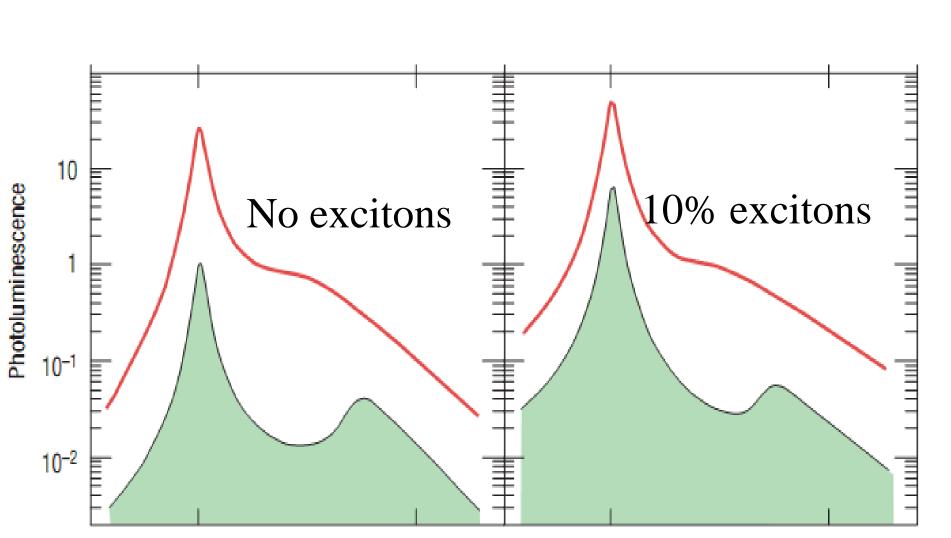
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Summary

- Study of density-dependent ionization-equilibrium using photoluminescence spectroscopy
- PL intensity ratio between exciton and band-edge peak measures exciton ionization equilibrium density (following Kira and Koch)
- Coulomb-correlated-plasma contribution is not important at 4K but dominates PL at exciton energy after ~100K.
- Approach to Mott transition directly observed through excitation-correlation PL dynamics
- Exciton formation times compete with radiative lifetimes at power

Kira-Koch Luminescence Formula¹



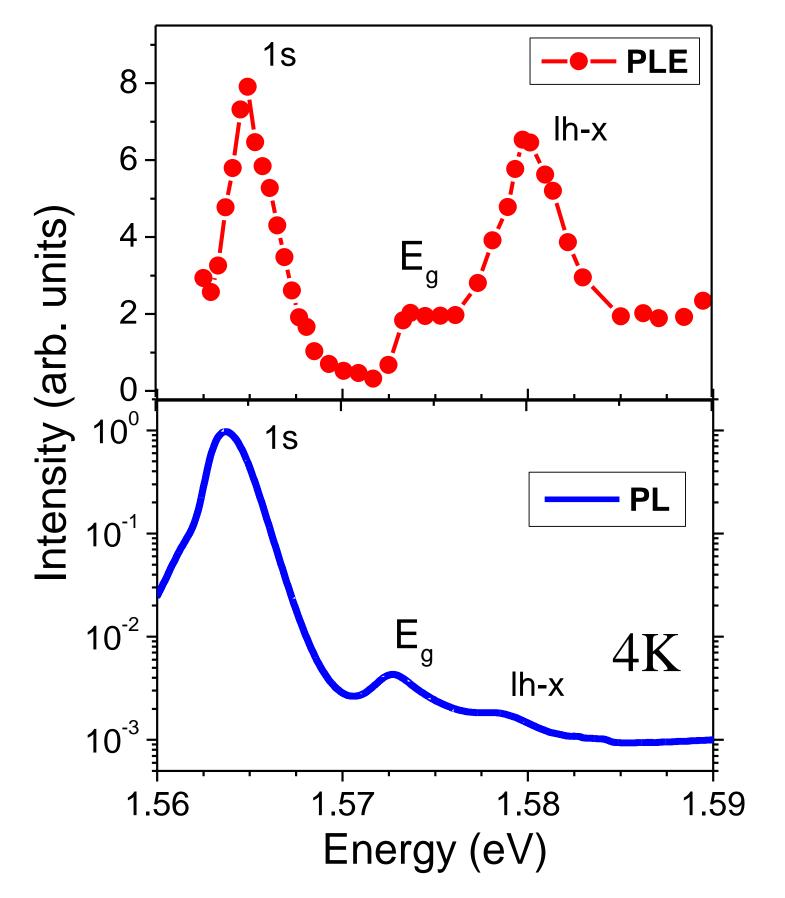


 $(\hbar\omega - E_{1s})$ (meV) Calculations by Kira, Koch and Coworkers

- Plasma can contribute to emission at exciton energy
- Q. How significant is this contribution?
- Q. How do we estimate the true exciton population?
- Intensity ratio between the 1s exciton and band-edge emission can give a clue?
- Study of the Mott transition in this light

Relevant references:

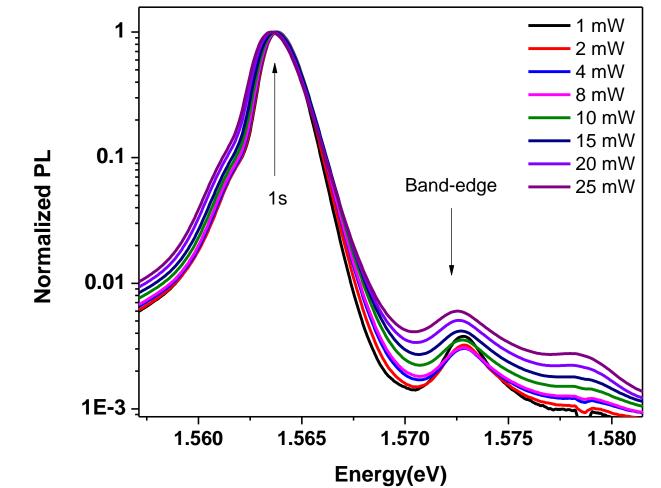
- M. Kira and S. W. Koch Semiconductor Quantum Optics (Cambridge 2012)
- 2. S. Chatterjee, et al. Phys Rev Lett 92, 067402 (2004). 3. J. Szczytko, et al. Phys. Rev B 71, 195313 (2005).
- 4. Literature on excitonic Mott transition



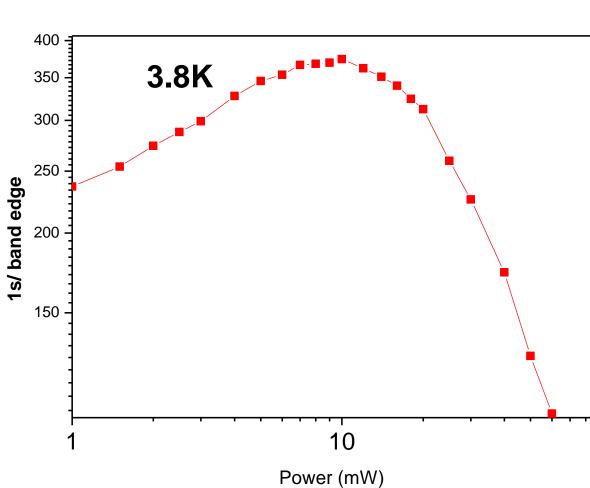
Experimental

- Special Sample: Both 1s exciton and band-edge emission seen in PL => Can estimate relative populations from the PL spectra
- 8nm, multi-quantum well GaAs sample
- Experiments: PL, PLE, pump-probe reflectivity and dephasing dynamics
- Here we will only study the ratios of 1s to band-edge emission intensities. At low temperature, ratio >100

Excitation power-dependent PL spectra



1.5634 -1.5632 1s peak position



Normalized PL spectra for different power

Observations:

The ratio between 1s peak to band-edge Red shift with power, heating? peak intensity as function of power.

• Qualitatively PL spectra look similar as excitation power is increased but are quantitatively different.

- As the excitation power increased that ratio first increase up to a certain power. Why? Then it falls sharply. Why?
- Small red-shift with excitation power (Bandgap renormalization or heating?)

0.0001 Carrier Density n (µm⁻²)

Calculated bright exciton fraction in Chatterjee, et al. PRL 92, 067402 (2004). Our experimental trend is similar. But we claim that the bright exciton fraction is orders of magnitude larger. Their analysis is flawed due to the use of KMS relation. Discussion on why KMS relation should not be used to convert PL into absorption: R. Bhattacharya, et al. Appl Phys Lett 100, 222103 (2012).

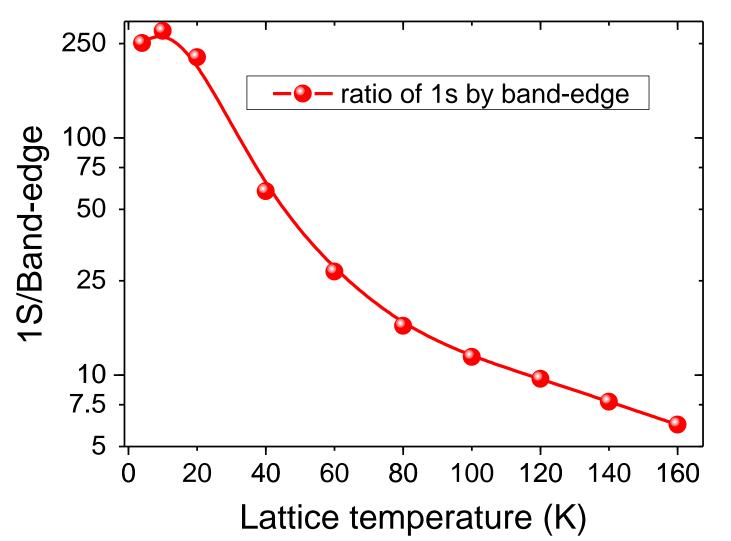
Simple analysis seems to work

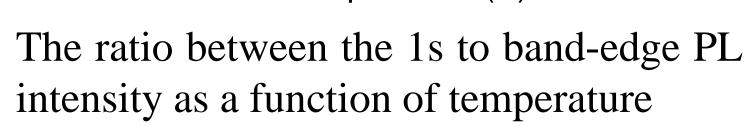
If 1s to band-edge peak PL emission intensity ratio is due to Coulomb-correlated plasma only

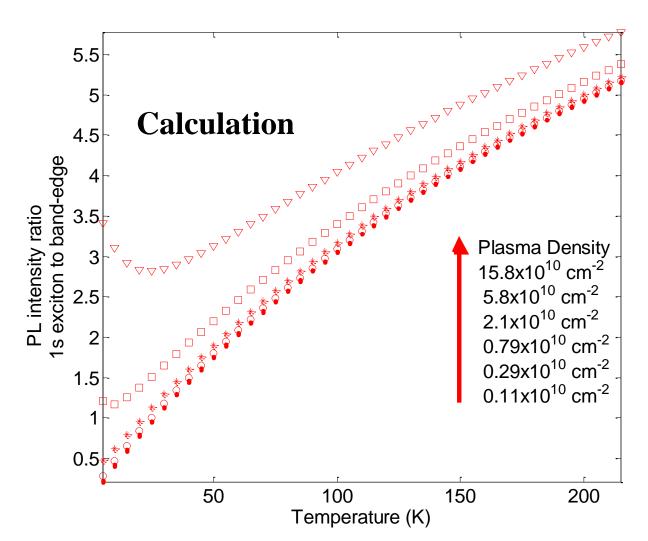
$$R = \frac{|\phi^{1S}(r=o)|^2 \int |\phi^{1S}(k)|^2 f_e(k) f_h(k) dk}{|\phi^{free}(r=o)|^2 f_e(k=0) f_h(k=0)} \le 16$$
 ; $|\phi^{free}(r=o)|^2$: Sommerfeld factor

Qualitatively

- Kira-Koch analysis suggests that we definitely have real excitons if R > 16
- Experimentally $R > 100 \implies$ emission at low temperature is mostly from excitons



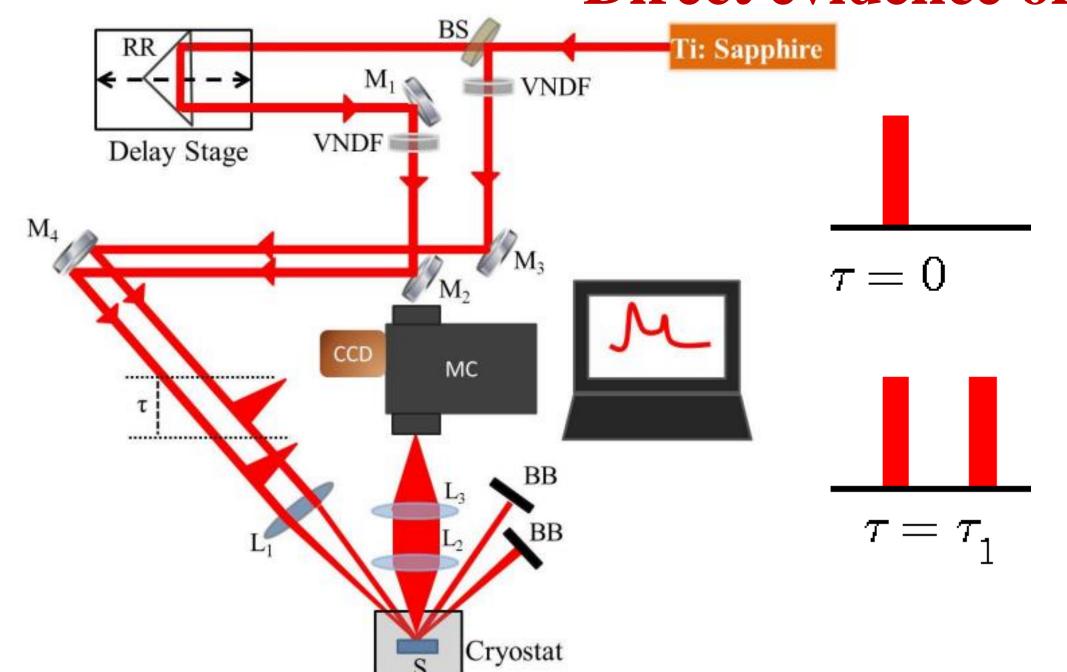




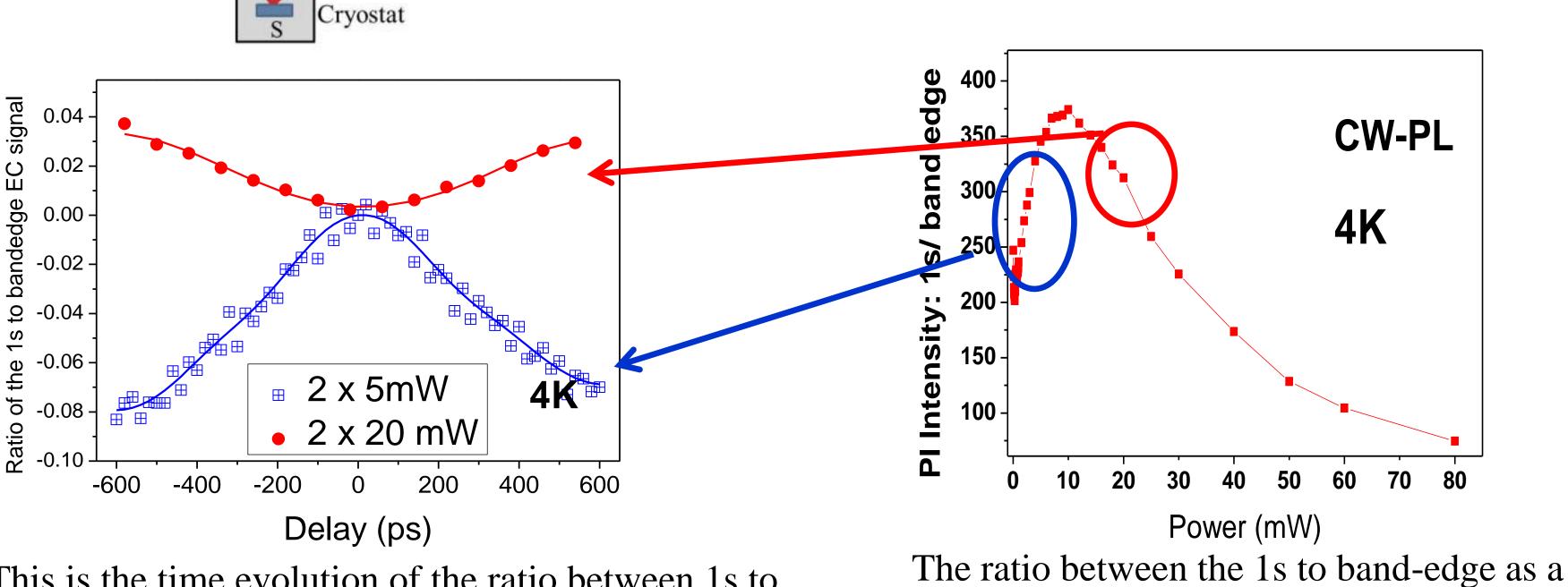
Theoretical plot of the ratio (1s/band-edge) as a function of temperature for different plasma densities

- Binding energy of 1s excition is about 9 meV \approx 104 K => most excitions are ionized at 160 K
- At higher temperature, essentially only e-h plasma exists with no bound states
- Kira-Koch argument seems relevant at high temperature (why we see exciton peak at high temperature)
- Our calculated value of the ratio approaches ~ 5 same as experimental value at higher temperature

Picosecond excitation-correlation study of ionization ratio Direct evidence of Mott transition



- Picosecond excitation correlation PL spectroscopy is a two-beam time-resolved correlation technique Suitable for study of nonlinearity
- The number of photon incident on the sample is constant whatever the delay between the two pulses
- Spectrally resolved and time—integrated PL spectra is measured at given delay using CCD



This is the time evolution of the ratio between 1s to band-edge.

function of power

Results

- EC signal ratio at low power increases as the delay approaches zero => exciton population increases with carrier density. Reverse of Mott transition: Competition between exciton formation and recombination times
- EC signal ratio reverses at higher power=> Mott transition
- Power-dependent heating is not important for this measurement
- Exciton formation times are within about an order of magnitude of recombination times (detailed analysis in progress)

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